



Docket No.: M4065.0019/P019-A  
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:  
Leonard Forbes, et al.

Application No.: 09/750,111

Art Unit: 2822

Filed: December 29, 2000

Examiner: K. Rose

For: HIGH DENSITY SRAM CELL WITH  
LATCHED VERTICAL TRANSISTORS

AMENDMENT AFTER FINAL ACTION (37 C.F.R. SECTION 1.116)

MS AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

In response to the Office Action dated August 25, 2003 (Paper No. 11), finally rejecting claims 1-33, please amend the above-identified U.S. patent application as follows:

**Amendments to the Claims** are reflected in the listing of claims, which begins on page 2 of this paper.

Please consider the **Remarks**, which begin on page 8 of this paper.

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